

	L #	Hits	Search Text	DBs	Time Stamp
1	L23	2	miniature adj micromachined adj unit	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/03/2 5 14:52
2	L24	446	oxinitride	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/03/2 5 14:52
3	L25	12830	oxynitride	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/03/2 5 14:53
4	L26	0	(oxynitride and silicon adj dioxide) near4 waveguide	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/03/2 5 14:54

	L #	Hits	Search Text	DBs	Time Stamp
5	L27	0	((oxynitride or oxinitride) and silicon adj dioxide) near4 waveguide	USPAT; US-PGPUB; ; EPO; JPO; DERWENT; IBM-TDB	2003/03/25 14:55
6	L28	0	((oxynitride or oxinitride) and silicon adj dioxide) near10 waveguide	USPAT; US-PGPUB; ; EPO; JPO; DERWENT; IBM-TDB	2003/03/25 14:55
7	L29	49	oxynitride near4 waveguide	USPAT; US-PGPUB; ; EPO; JPO; DERWENT; IBM-TDB	2003/03/25 14:57
8	L30	5	oxinitride near4 waveguide	USPAT; US-PGPUB; ; EPO; JPO; DERWENT; IBM-TDB	2003/03/25 15:11

	L #	Hits	Search Text	DBs	Time Stamp
9	L33	0	oxinitride near6 waveguide and antireflection adj2 coating	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/03/2 5 15:14
10	L34	0	oxynitride near6 waveguide and antireflection adj2 coating	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/03/2 5 15:14

	Document ID	Issue Date	Pages	Title	Current OR
1	US 20020037025 A1	20020328	11	Hybrid narrow -linewidth semiconductor lasers	372/50
2	US 6480513 B1	20021112	10	Tunable external cavity laser	372/20
3	US 6101210 A	20000808	8	External cavity laser	372/96
4	US 6438287 B1	20020820	5	Dispersion compensation	385/27
5	US 5894492 A	19990413	25	Semiconductor laser with integral spatial mode filter	372/50
6	US 5499261 A	19960312	24	Light emitting optical device with on-chip external cavity reflector	372/50
7	US 6316281 B1	20011113	24	Method for fabricating a hybrid optical integrated circuit employing SOI optical waveguide	438/31
8	US 5827102 A	19981027	7	Low temperature method for evacuating and sealing field emission displays	445/25
9	US 6222967 B1	20010424	55	Packaging platform, optical module using the platform, and methods for producing the platform and the module	385/49
10	US 5773875 A	19980630	9	High performance, low thermal loss, bi-temperature superconductive device	257/661
11	US 5780314 A	19980714	8	Method of forming a high performance low thermal loss bi-temperature superconductive device	438/2

	Current XRef	Retrieval Classif	Inventor
1	372/36; 372/96		Bartman, Randall K. et al.
2	372/102; 372/34; 372/6; 372/64; 372/92		Kapany, Narinder S. et al.
3	359/27; 372/101; 372/98		Bestwick, Timothy David et al.
4	359/341.1; 385/24; 385/37; 385/39		Jones, Kevan P
5	359/344; 372/18; 372/20; 372/97; 372/99		Welch, David F. et al.
6	372/44; 372/46; 372/93; 372/99		Welch, David F. et al.
7	385/14; 385/49		Lee, Sang Hwan et al.
8	445/43		Watkins, Charles M. et al.
9	385/88; 385/92		Amano, Michiyuki et al.
10	257/662; 257/716; 257/E27.00 7; 505/703; 505/856		Chan, Hugo Wai-Kung
11	257/E27.00 7		Chan, Hugo Wai-Kung

	Document ID	Issue Date	Pages	Title	Current OR
12	US 5644667 A	19970701	61	Integrated semiconductor optical devices and method of manufacture employing substrate having alignment groove	385/49
13	US 6335793 B1	20020101	16	Planar waveguide chemical sensor	356/477

	Current XRef	Retrieval Classif	Inventor
12	385/131; 385/83; 385/92		Tabuchi, Haruhiko
13	356/481		Freeman, Neville John et al.